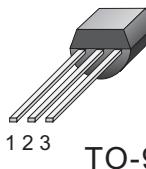


### HAOPIN MICROELECTRONICS CO.,LTD.

#### Description

Passivated, sensitive gate triacs in a plastic envelope, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

Symbol		Simplified outline
T2	T1	 TO-92
Pin	Description	
1	Main terminal 1(T1)	
2	Gate	
3	Main terminal 2 (T2)	

#### Applications:

- ◆ Motor control
- ◆ Industrial and domestic lighting
- ◆ Heating
- ◆ Static switching

#### Features

- ◆ Blocking voltage to 600 V
- ◆ On-state RMS current to 2 A

SYMBOL	PARAMETER	Value	Unit
$V_{DRM}$	Repetitive peak off-state voltages	600	V
$I_T \text{ (RMS)}$	RMS on-state current	2	A
$I_{TSM}$	Non-repetitive peak on-state current	10	A

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$R_{thj-mb}$	Thermal resistance, Junction to mounting base	Full cycle	-	-	60	K/W
		Half cycle	-	-	80	K/W
$R_{th(j-a)}$	Thermal resistance, Junction to Ambient	Pcb mounted; lead length=4mm	-	150	-	K/W



# 2CQ60

## Sensitive Gate Triacs

HAOPIN MICROELECTRONICS CO.,LTD.

Limiting values in accordance with the Maximum system(IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN	Value	UNIT
$V_{DRM}$	Repetitive peak off-state Voltages		-	600	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{lead} \leq 50^\circ\text{C}$	-	2	A
$I_{TSM}$	Non-repetitive peak on-state current	full sine wave; half sine wave	- -	10 12	A
$P_{G(AV)}$	Average gate power	Over any 20 ms period	-	0.3	W
$I_{GM}$	Peak gate current		-	0.2	A
$T_L$	Lead temperature 1.6mm from case for 10 seconds		-	230	°C
$T_{stg}$	Storage temperature range		-40	150	°C
$T_c$	Operating case Temperature range		-40	110	°C

$T_j=25^\circ\text{C}$  unless otherwise stated

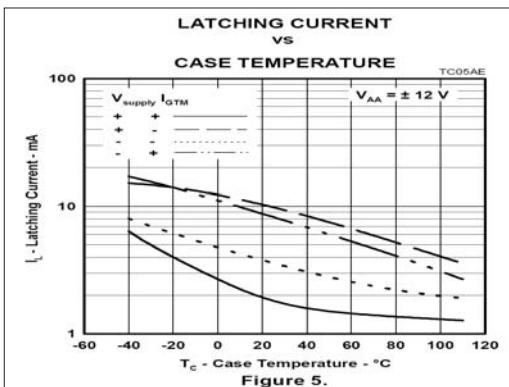
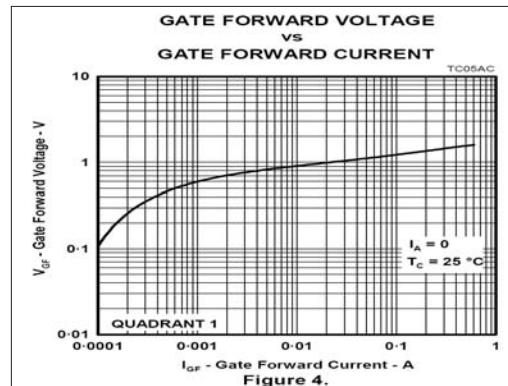
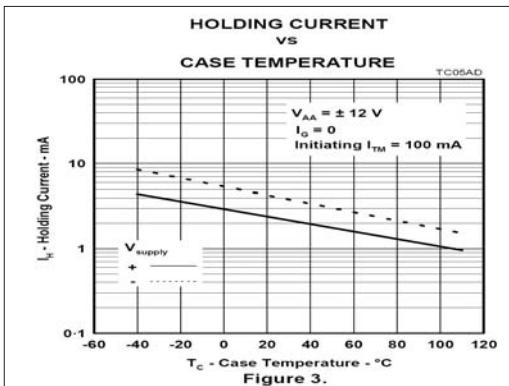
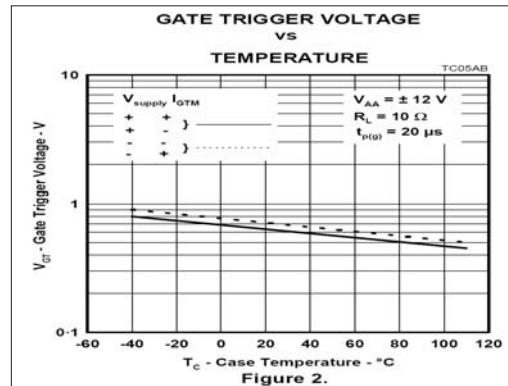
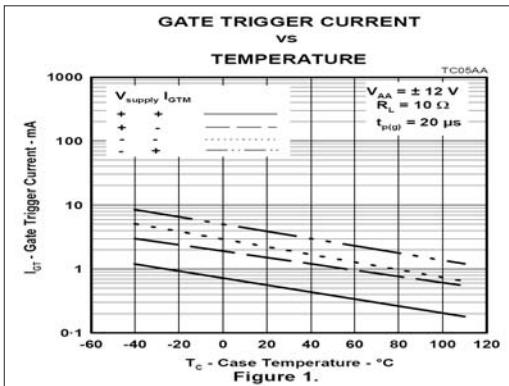
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
Static characteristics						
$I_{GT}$	Gate trigger current	$V_D=12\text{V}; I_T=0.1\text{A}$	- -	-	8 10	mA
$V_{GT}$	Latching current	$V_D=12\text{V}; I_T=0.1\text{A}$ $V_D=400\text{V}; I_T=0.1\text{A}; T_j=150^\circ\text{C}$	-	-	2.5	V
$I_H$	Holding current	$V_D=12\text{V}; I_{GT}=0.1\text{A}$	-	-	30	mA
$I_L$	Latching current	$V_D=12\text{V}; I_{GT}=0.1\text{A}$	-	-	40	mA

Dynamic Characteristics

$V_{TM}$	Peak on-state voltage	$I_{TM}=2.0\text{A}$	-	-	2.2	V
$I_{DRM}$	Repetitive peak off-state current	$V_D=\text{rated} V_{DRM}$ $I_G=0$	-	-	$\pm 20$	$\mu\text{A}$

**HAOPIN MICROELECTRONICS CO.,LTD.**

### Description



HAOPIN MICROELECTRONICS CO.,LTD.

## MECHANICAL DATA

Dimensions in mm

Net Mass: 0.2 g

TO-92

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		1.35			0.053	
B			4.70			0.185
C		2.54			0.100	
D	4.40			0.173		
E	12.70			0.500		
F			3.70			0.146
a			0.50			0.019

